

## **General Description**

SSF202 is a small 8pin DFN packaged customized ASIC with configurable parameters. It supports frequency division and in-phase output function.

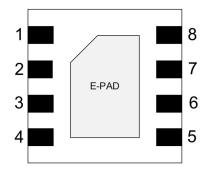
#### **Features**

- Power supply input: 2.3V~5.5V
- OUT1, 1x Push Pull Digital Output, 12.288Mhz output
- OUT2, 1x Push Pull Digital Output, 6.144Mhz output
- GND Power Ground
- OUT3, 1x Push Pull Digital Output 96Khz output
- NC Not Connected, Internal pull-down 1M
- IN Digital input with Schmitt, Internal pull-down 1M, 24.576Mhz input
- DFN 8 Package

## **Applications**

- Ultra low power consumption
- Pb Free and RoHS Compliant and Halogen Free

### **Pin Configurations**

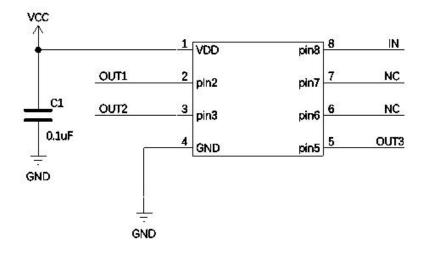


2.0mm x 2.0mm 8 Pin DFN Top View

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## **Block Diagram**



#### Note:

- 1. Voltage on any pin must be with in GND to VDD.
- 2. ESD protect is must be considered on all Pins which connected to external interface.

#### Pin name

Pin	Pin	ТҮРЕ	Function
1	VDD	Power	Power supply input, 2.3V~5.5V
2	OUT1	1x Push Pull Digital Output	12.288Mhz output.
3	OUT2	1x Push Pull Digital Output	6.144Mhz output.
4	GND	Power	Ground
5	OUT3	1x Push Pull Digital Output	96Khz output.
6	NC	Not Connected	Internal pull-down 1M
7	NC	Not Connected	Internal pull-down 1M
8	IN	Digital input with Schmitt	Internal pull-down 1M, 24.576Mhz input.

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# **Absolute Maximum Ratings**

Parameter	Min.	Max.	Unit
Supply Voltage on VDD to GND	-0.3	7	V
Maximum Voltage Input to Pins	-0.3	7	V
VDD to GND Maximum DC Current		90	mA
Input Leakage Current		1000	nA
Storage Temperature Range	-65	150	°C
Junction Temperature		150	°C
ESD Protection (HBM)	2000		V
ESD Protection (CDM)	500		V
Moisture Sensitivity Level (MSL)		1	

#### **Customize Electrical Characteristics**

VDD = $3.3V\pm10\%$ , Temp= $25^{\circ}$ C

Symbol	Parameter	Condition/Note	Min.	Тур.	Max.	Unit
lα	Quiescent Current	Static inputs and floating outputs		0.1		μΑ

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# **Electrical Characteristics**

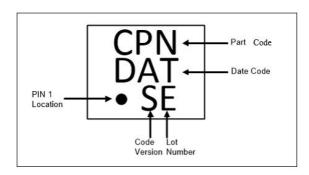
VDD =3.3V±10%, Temp: -40~85°C

Symbol	Parameter	Condition/Note	Min.	Тур.	Max.	Uni
V <sub>DD</sub>	Supply Voltage		1.71	3.3	5.5	٧
T <sub>A</sub>	Operating Temperature		-40	25	85	°C
C <sub>VDD</sub>	Capacitor Value at VDD			0.1		μF
I <sub>IH</sub>	HIGH-Level Input Current	Logic Input PINs; V <sub>IN</sub> = VDD	-1.0		1.0	μΔ
I <sub>IL</sub>	LOW-Level Input Current	Logic Input PINs; V <sub>IN</sub> = 0V	-1.0		1.0	μΑ
POR			1			
$PON_{THR}$	Power On Threshold	VDD Level Required to Start Up	1.67	1.80	1.92	V
POFF <sub>THR</sub>	Power Off Threshold	VDD Level Required to Switch Off	0.95	1.25	1.54	V
$T_{SU}$	Startup Time	From VDD rising past PON <sub>THR</sub>		1.2	1.6	m
I <sub>stand_by</sub>		T=+25℃		97		n <i>A</i>
O PIN						
	HIGH-Level Input Voltage	Logic Input	1.90			V
$V_{IH}$		Logic Input with Schmitt Trigger	2.11			٧
		Low-Level Logic Input	0.92			V
	LOW-Level Input Voltage	Logic Input			1.30	V
$V_{IL}$		Logic Input with Schmitt Trigger			1.16	V
		Low-Level Logic Input			0.77	V
V <sub>HYS</sub>	SchmittTrigger Hysteresis Voltage	Logic Input with Schmitt Trigger		0.45		V
I <sub>LKG</sub>	Input leakage (Absolute Value)			1	1000	n.
PON <sub>THR</sub> POFF <sub>THR</sub> T <sub>SU</sub> I <sub>stand_by</sub> O PIN  V <sub>IH</sub> V <sub>IL</sub>	HIGH-Level Outpu Voltage	Push-Pull, I <sub>OH</sub> = 3 mA, 1X Drive	2.60			٧
VOH		Push-Pull, I <sub>OH</sub> = 3 mA, 2X Drive	2.80			٧
	LOW-Level Output Voltage	Push-Pull, I <sub>OL</sub> = 3 mA, 1X Drive			0.25	ν
		Push-Pull, I <sub>OL</sub> = 3 mA, 2X Drive			0.22	٧
V <sub>OL</sub>		Open Drain, I <sub>OL</sub> = 3 mA, 1X Drive			0.12	V
		Open Drain, I <sub>OL</sub> = 3 mA, 2X Drive			0.089	V
I <sub>OH</sub>	HIGH-Level Output Pulse Current (see Note)	Push-Pull, V <sub>OH</sub> = 2.4 V , 1X Drive	5			m
		Push-Pull, V <sub>OH</sub> = 2.4 V, 2X Drive	10			m
I <sub>OL</sub>	LOW-Level Output Pulse Current (see Note)	Push-Pull, V <sub>OL</sub> = 0.4 V, 1X Drive	5			m
		Push-Pull, V <sub>OL</sub> = 0.4 V, 2X Drive	10			m
		Open Drain, V <sub>OL</sub> = 0.4 V, 1X Drive	15			m.
		Open Drain, V <sub>OL</sub> = 0.4 V, 2X Drive	30			m.

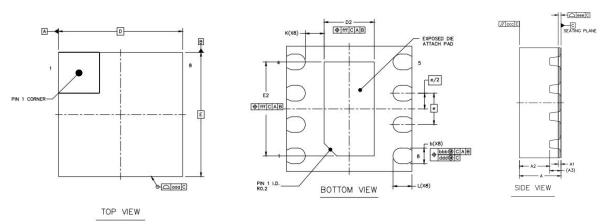
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## **Package Top Marking**



# **Package Drawing and Dimensions**



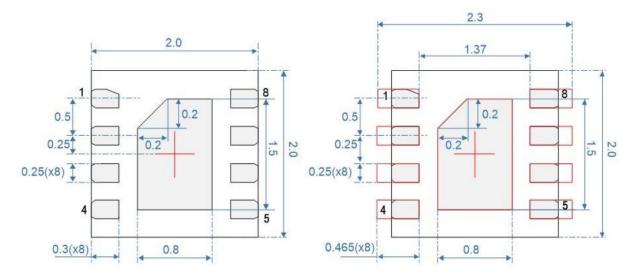
		SYMBOL	MIN	NOM	MAX	
TOTAL THICKNESS		A	0.7	0.75	0.8	
STAND OFF		A1	0	0.02	0.05	
MOLD THICKNESS		A2		0.55		
L/F THICKNESS		A3	0.203 REF			
LEAD WIDTH		ь	0.2	0.25	0.3	
BODY SIZE	×	D	2 BSC			
BODT SIZE	Y	E	2 BSC			
LEAD PITCH		e	0.5 BSC			
EP SIZE	×	D2	0.7	0.8	0.9	
EF SIZE	Y	E2	1.4	1.5	1.6	
LEAD LENGTH		L	0.2	0.3	0.4	
LEAD TIP TO EXPOSED I	PAD EDGE	к	0.3 REF			
PACKAGE EDGE TOLERAN	NCE	aaa	0.1			
MOLD FLATNESS		ccc	0.1			
COPLANARITY		eee	0.05			
LEAD OFFSET		bbb	0.1			
		ddd	0.05			
EXPOSED PAD OFFSET		fff	0.1			

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## **Recommended Land Patter**

Unit: mm



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